

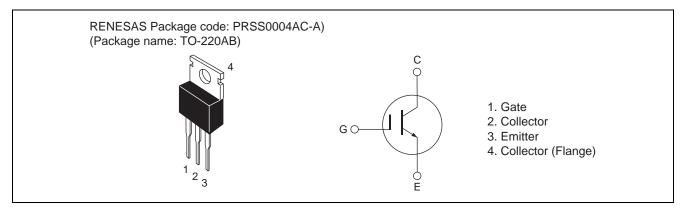
# RJP6085DPN

Silicon N Channel IGBT High Speed Power Switching

## Features

- High speed switching
- Low collector to emitter saturation voltage

## Outline



## **Absolute Maximum Ratings**

			$(Ta = 25^{\circ}C)$
ltem	Symbol	Ratings	Unit
Collector to Emitter voltage	V <sub>CES</sub>	600	V
Gate to Emitter voltage	V <sub>GES</sub>	±30	V
Collector current	I <sub>C</sub>	40	A
Collector peak current	I <sub>C(peak)</sub> Note1	80	A
Collector dissipation	P <sub>C</sub> <sup>Note2</sup>	178.5	W
Junction to case thermal impedance	θj-c <sup>Note2</sup>	0.7	°C/W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	С°

Notes: 1. Pulse width limited by safe operating area.

2. Value at  $Tc = 25^{\circ}C$ 

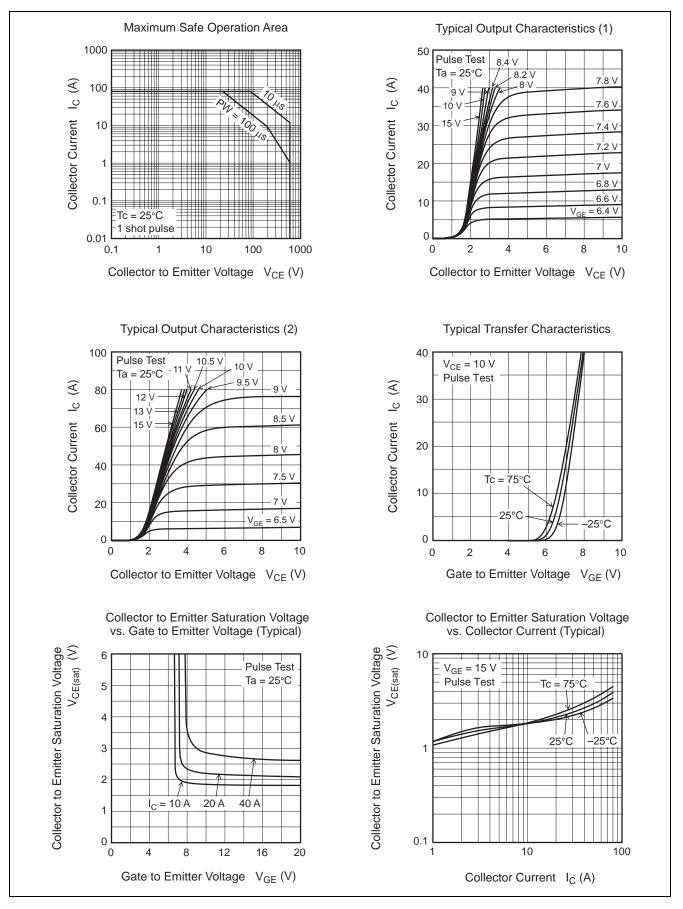
REJ03G1863-0100 Rev.1.00 Nov 09, 2009

## **Electrical Characteristics**

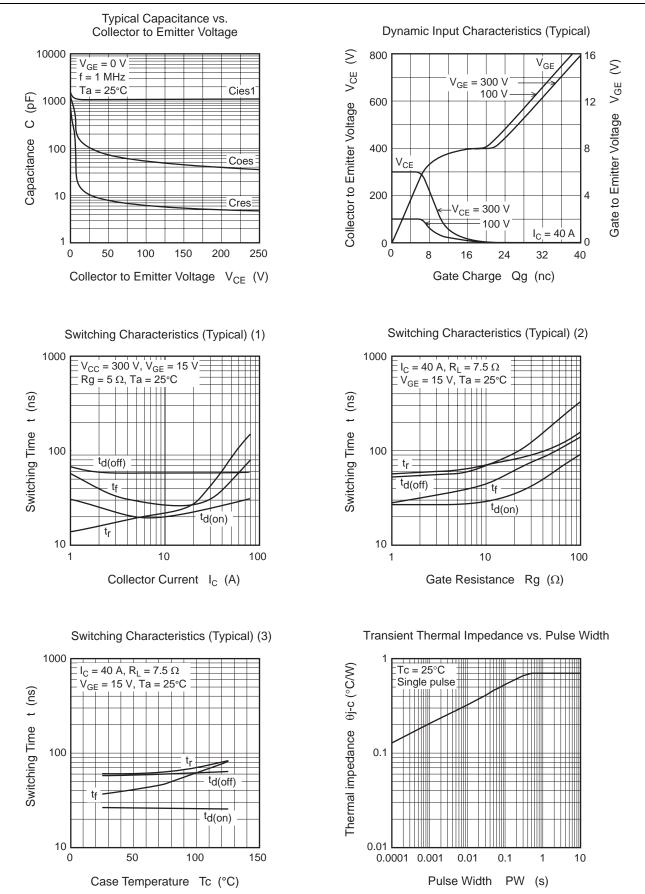
						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current	I <sub>CES</sub>	—	—	10	μΑ	$V_{CE} = 600 V, V_{GE} = 0 V$
Gate to emitter leak current	I <sub>GES</sub>	—	—	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0 \text{ V}$
Gate to emitter cutoff voltage	V <sub>GE(off)</sub>	4		6	V	$V_{CE} = 10V, I_C = 1 \text{ mA}$
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	2.65	3.5	V	$I_{C} = 40 \text{ A}, V_{GE} = 15V^{Note3}$
Input capacitance	Cies	_	1150	_	pF	V <sub>CE</sub> = 25V
Output capacitance	Coes	_	105	_	pF	V <sub>GE</sub> = 0 V f = 1MHz
Reveres transfer capacitance	Cres	_	12	_	pF	
Switching time	t <sub>d(on)</sub>	_	30	_	ns	I <sub>C</sub> = 40 A, Resistive Load
	tr	_	60	_	ns	$V_{CC} = 300V$
	t <sub>d(off)</sub>	_	60	_	ns	V <sub>GE</sub> = 15V
	t <sub>f</sub>		40		ns	Rg = 5 Ω

Notes: 3. Pulse test

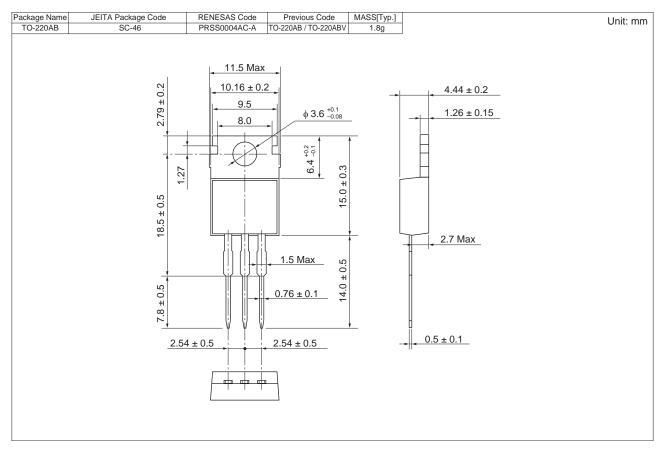
## **Main Characteristics**



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## **Package Dimensions**



## **Ordering Information**

Part No.	Quantity	Shipping Container
RJP6085DPN-00-T2	600 pcs	Box (Tube)

## RenesasTechnology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

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Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510

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